# NSN 5961-01-007-5842

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Inclosure Material:

Metal

**Overall Length:** 

0.297 inches

# **Overall Diameter:**

0.620 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release5861 professional/industrial association specification

#### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

No

# Fiig:

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